

Abstract Submitted  
for the MAR09 Meeting of  
The American Physical Society

**Observation of Fractional Microwave-Induced Resistance Oscillations using Co-Planar Waveguide on High-Mobility 2DES** KRISTJAN STONE, RUI-RUI DU, Rice University, LOREN PFEIFFER, KEN WEST, Bell Laboratories, Alcatel-Lucent — The microwave-induced resistance oscillations (MIRO) are commonly observed in high-mobility GaAs 2D electron systems (2DES) irradiated by microwaves. Usually this is accomplished using an antenna or waveguide, where the electromagnetic components ( $E_\omega$  and  $H_\omega$ ) coincide with the 2DES plane. We explore MIRO in a co-planar waveguide (CPW) geometry, in which  $E_\omega$  is the dominant excitation component in the 2DES plane. Our samples are Hall bars of high-mobility,  $\mu = (6 - 12) \times 10^6$  cm<sup>2</sup>/Vs, GaAs/Al<sub>x</sub>Ga<sub>1-x</sub>As quantum wells with electron densities ranging from 3 to  $5 \times 10^{11}$  cm<sup>-2</sup>. Microwaves from a tunable source (2 - 40 GHz) were fed in, via a semi-rigid coax cable, to an impedance-matched CPW across the length of the Hall bar, and brought out via a similar semi-rigid coax to a power sensor. Using this CPW geometry, we are able to simultaneously measure the photoconductivity and the microwave transmission across the sample. In a temperature range of 2.0 K - 5.0 K, we observed fractional MIRO associated with  $\varepsilon = 1/2, 1/3, 1/4,$  and  $1/5$ , where  $\varepsilon = \omega/\omega_c$ , and  $\omega_c$  is the cyclotron frequency. Experimental data as well as a brief discussion will be presented. The work at Rice was funded by NSF DMR-0706634.

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Date submitted: 19 Nov 2008

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